

SPECIFICATION SHEET

SPECIFICATION SHEET NO.	N0310-D0411N4007A10A
DATE	Mar. 10, 2021
REVISION	A0
DESCRIPITION	Axial Lead General Purpose Silicon Rectifier, DO-41 series,
	1N4007 – T/B Type 2 Pins
	Reverse Voltage 1000V Max. Forward Current 1.0A Max.
	Operating Temp. Range -55°C ~+150°C
	Package in AMMO Pack, 5000pcs/Tape, Tape/Box
	RoHS/RoHS III compliant
CUSTOMER	
CUSTOMER PART NUMBER	
CROSS REF. PART NUMBER	
ORIGINAL PART NUMBER	MDD 1N4007 – T/B
PART CODE	DO411N4007A10A

VENDOR APPROVE

Issued/Checked/Approved







DATE: March 10, 2021

USTOMER APPROVE	
ATE:	



GENERAL PURPOSE SILICON RECTIFIER DO-41 SERIES

MAIN FEATURE





- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Fast switching for high efficiency
- · High forward surge current capability
- High temperature soldering guaranteed, 250 °C/10 seconds at terminals
- Low reverse leakage

APPLICATION

• For printed circuit board

PART CODE GUIDE

REQUEST FOR Quotation

DO41	1N4007	Α	10A
1	2	3	4

1) **DO41**: Axial Lead General Purpose Silicon Rectifier, 2 Pins, DO-41 series

2) 1N4007: Type code for original part number 1N4007-T/B

3) A: Package code, Package in AMMO Pack, 5000pcs/Tape, Tape/Box

4) 10A: Specification code for Reverse Voltage 1000V Max. Forward Current 1.0A Max.

MORE ITEMS AVAILABLE

DO41IN4001A105	DO41IN4002A110	DO41IN4003A120	DO41IN4004A140	DO41IN4005A160
DO41IN4007A10A				



GENERAL PURPOSE SILICON RECTIFIER DO-41 SERIES

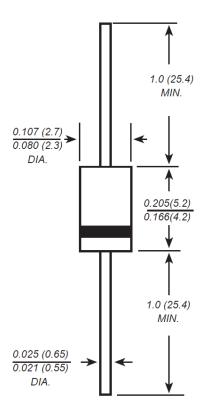
DIMENSION (Unit: Inch/mm)





Marking: 1N4007

DO-41





GENERAL PURPOSE SILICON RECTIFIER DO-41 SERIES

MECHANICAL DATA

Ca	ase	Terminals	Polarity	Mounting Position	Weight per piece
	-41 molded c body	Solder plated, Solderable per MIL-STD-750, Method 2026	Polarity symbol marking on case	Any	0.012 Ounce, 0.373 grams

MAX. RATING & CHARACTERISTICS

Parameter		SYMBOLS	VALUE			UNITS
			Min.	Typical	Max.	
Repetitive peak reverse voltage		V RRM			1000	Volts
RMS voltage		V RMS			700	Volts
DC blocking voltage		V DC			1000	Volts
Average forward output rectified current at TL= 110°C Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) Instantaneous forward voltage at 1.0A		I AV			1.0	А
		I FSM		30		A
		VF			1.10	Volts
DC reverse current at rated DC					5	μΑ
blocking voltage					50	μΑ
Junction capacitance (Note 2) Thermal resistance (Note 3) Operating junction temperature range Storage temperature range		Cı		15		pF
		R QJA		50		°C/W
		TJ	-65		+150	°C
		Т ѕтб	-65		+150	°C

Note

- 1. Ratings at 25 C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0Voltage
- 3. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, PCB. Mounted.



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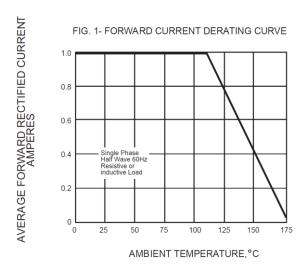
RELIABILITY

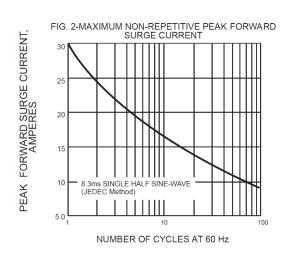
Number	Experiment Items	Experiment Method And Conditions	Reference Documents
1	Solder Resistance Test	Solder Resistance Test Test 260°C \pm 5°C for 10 \pm 2 sec. Immerse body into solder 1/16" \pm 1/32"	
2	Solderability Test	230°C ±5°C for 5 sec.	MIL-STD-750D METHOD-2026.1 0
3	Pull Test	1 kg in axial lead direction for 10 sec.	MIL-STD-750D METHOD-2036.4
4	Bend Test	0.5Kg Weight Applied To Each Lead, Bending Arcs 90 °C ± 5 °C For 3 Times	MIL-STD-750D METHOD-2036.4
5	High Temperature Reverse Bias Test	TA=100°C for 1000 Hours at VR=80% Rated VR	MIL-STD-750D METHOD-1038.4
6	Forward Operation Life Test	TA=25°C Rated Average Rectified Current	MIL-STD-750D METHOD-1027.3
7	Intermittent Operation Life Test	On state: 5 min with rated IRMS Power Off state: 5 min with Cool Forced Air. On and off for 1000 cycles.	MIL-STD-750D METHOD-1036.3
8	Pressure Cooker Test	15 PSIG, Ta=121°C, 4 hours	MIL-S-19500 APPENOIXC
9	Temperature Cycling Test	-55°C~+125°C; 30 Minutes For Dwelled Time 5 minutes for transferred time. Total: 10 cycles.	MIL-STD-750D METHOD-1051.7
10	Thermal Shock Test	0°C for 5 minutes., 100°C for 5minutes, Total: 10 cycles	MIL-STD-750D METHOD-1056.7
11	Forward Surge Test	8.3ms Single Sale Sine-wave One Surge.	MIL-STD-750D METHOD-4066.4
12	Humidity Test	Ta=65°C, RH=98% for 1000 hours.	MIL-STD-750D METHOD-1021.3
13	3 High Temperature Storage 150°C for 1000 Hours life Test		MIL-STD-750D METHOD-1031.5

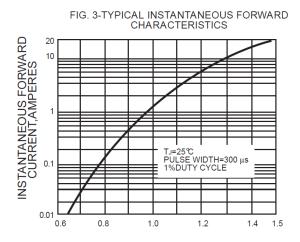


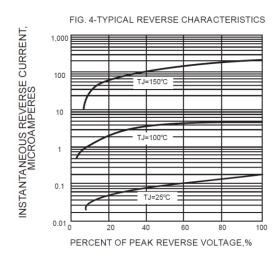
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RATINGS AND CHARACTERISTIC CURVES (For Reference Only)

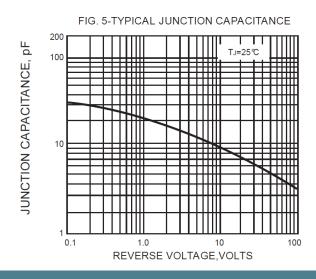


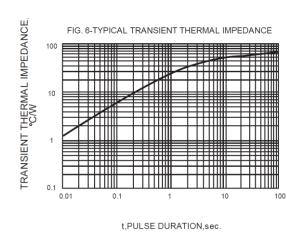






INSTANTANEOUS FORWARD VOLTAGE, VOLTS



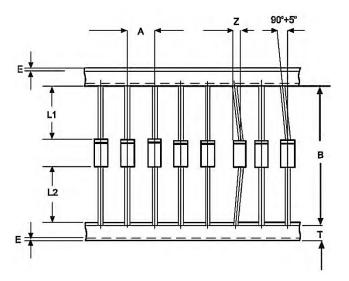


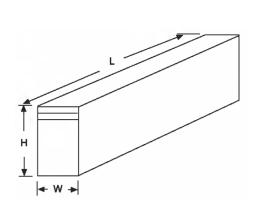


GENERAL PURPOSE SILICON RECTIFIER DO-41 SERIES

AMMO BOX (Unit: mm)

- All Devices are packed in accordance with EIA standard RS-296-D and specifications.
- Each component lead shall be sandwiched between taps for A minimum of 3.2 mm (-.126")





Item	Symbol	DO-41 Uni(mm)	DO-41 Unit (Inch)
Component Alignment	Z	1.2 Max.	0.048 Max.
Tape Width	Т	6.0 +/- 0.4	0.236 +/- 0.016
Exposed Adhesive	E	0.8 Max.	0.032 Max.
Body Eccentricity	L1 – L2	1.0 Max.	0.040 Max.
Component Pitch A (2.0mm/20 pitch)	А	5.0	0.197
Component Pitch B (2.0mm/20 pitch)	В	26.0	1.023
Component Pitch A (2.0mm/10 pitch)	А	5.0	0.197
Component Pitch B (2.0mm/10 pitch)	В	52.4	2.063
Box Length	L	255.0 +/- 5.0	10.04 +/- 0.197
Box Width	W	78.0 +/- 5.0	3.07 +/- 0.197
Box Height	Н	150.0 +/- 5.0	5.91 +/- 0.197



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AMMO PACK IN TAPE/BOX (Unit: mm)

Case Code	Qty. Per Reel (pcs)	Component Space (mm)	Tape Space (mm)	Inner Box L*W*H (mm)	Carton size L*W*H (mm)	Qty. Per Carton (pcs)	G. W (kg)
DO-41	5000	5.0	52.4	198*86*21	450*215*250	50,000	12.45

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